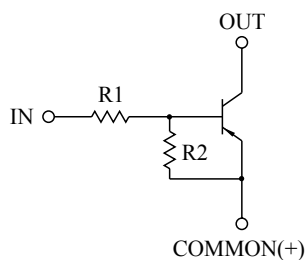


SWITCHING APPLICATION.  
INTERFACE CIRCUIT AND DRIVER CIRCUIT APPLICATION.

#### FEATURES

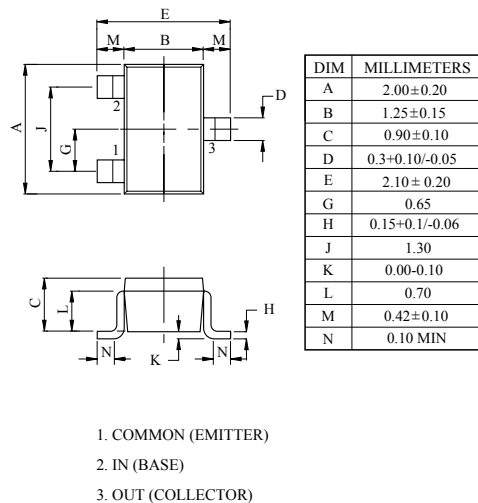
- With Built-in Bias Resistors
- Simplify Circuit Design
- Reduce a Quantity of Parts and Manufacturing Process
- High Packing Density.

#### EQUIVALENT CIRCUIT



#### BIAS RESISTOR VALUES

TYPE NO.	R1(k $\Omega$ )	R2(k $\Omega$ )
KRA307	10	47
KRA308	22	47
KRA309	47	22



USM

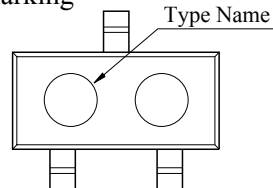
#### MAXIMUM RATING (Ta=25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Voltage	KRA307 ~ 309	$V_O$	-50	V
Input Voltage	KRA307	$V_I$	-30, 6	V
	KRA308		-40, 7	
	KRA309		-40, 15	
Output Current	KRA307 ~ 309	$I_O$	-100	mA
Power Dissipation		$P_D$	100	mW
Junction Temperature		$T_j$	150	°C
Storage Temperature Range		$T_{stg}$	-55 ~ 150	°C

#### MARK SPEC

TYPE	KRA307	KRA308	KRA309
MARK	PH	PI	PJ

#### Marking



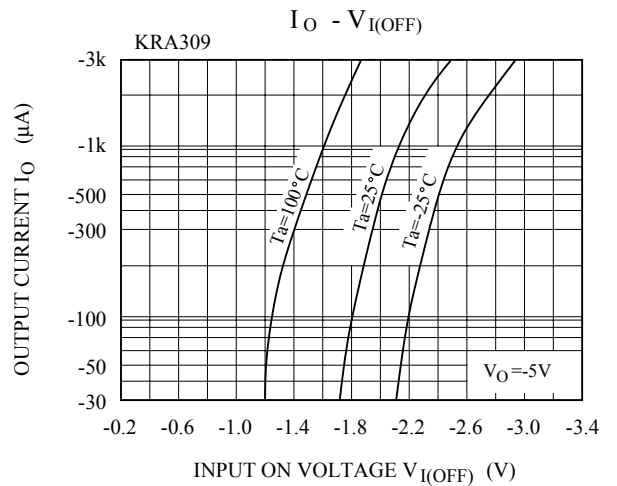
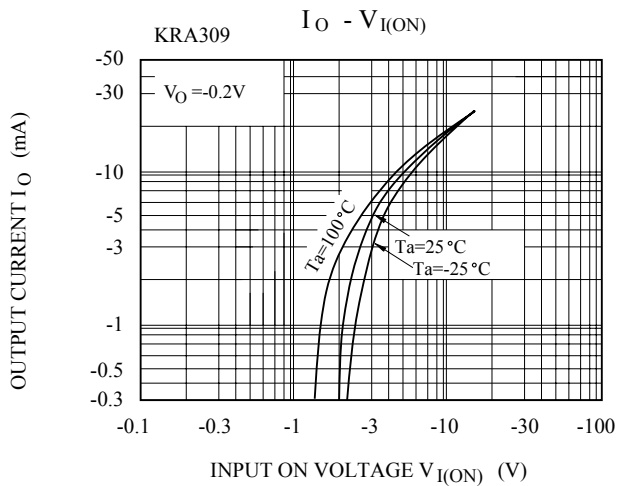
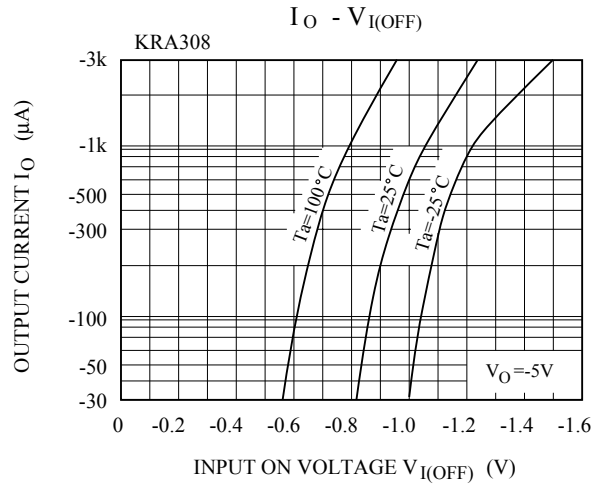
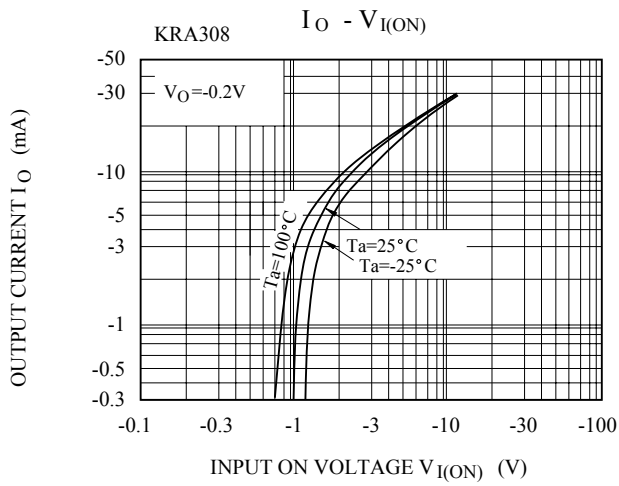
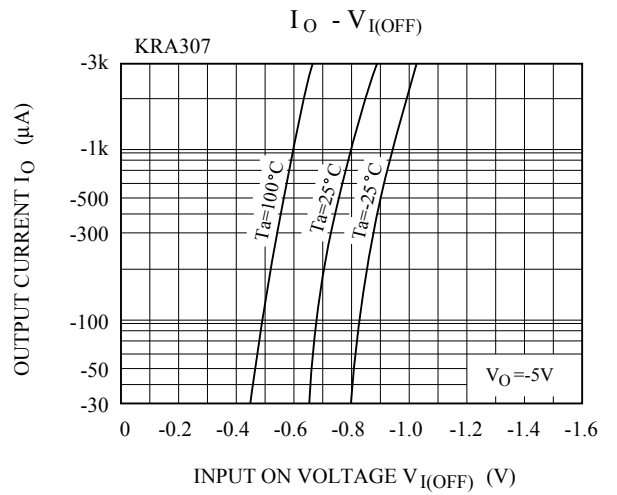
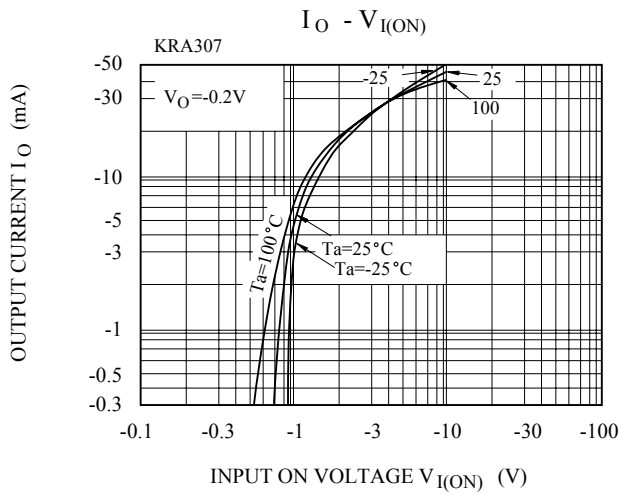
# KRA307~KRA309

## ELECTRICAL CHARACTERISTICS (Ta=25℃)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT		
Output Cut-off Current		KRA307 ~ 309	I <sub>O(OFF)</sub>	V <sub>O</sub> =-50V, V <sub>I</sub> =0	-	-	-500	nA	
DC Current Gain	KRA307	G <sub>I</sub>	V <sub>O</sub> =-5V, I <sub>O</sub> =-10mA	80	150	-			
	KRA308			80	150	-			
	KRA309			70	140	-			
Output Voltage		KRA307 ~ 309	V <sub>O(ON)</sub>	I <sub>O</sub> =-10mA, I <sub>I</sub> =-0.5mA	-	-0.1	-0.3	V	
Input Voltage (ON)	KRA307	V <sub>I(ON)</sub>	V <sub>O</sub> =-0.2V, I <sub>O</sub> =-5mA	-	-1.2	-1.8	V		
	KRA308			-	-1.8	-2.6			
	KRA309			-	-3.0	-5.8			
Input Votlage (OFF)	KRA307	V <sub>I(OFF)</sub>	V <sub>O</sub> =-5V, I <sub>O</sub> =-0.1mA	-0.5	-0.75	-	V		
	KRA308			-0.6	-0.88	-			
	KRA309			-1.5	-1.82	-			
Transition Frequency		KRA307 ~ 309	f <sub>T</sub> *	V <sub>O</sub> =-10V, I <sub>O</sub> =-5mA	-	200	-	MHz	
Input Current	KRA307	I <sub>I</sub>	V <sub>I</sub> =-5V	-	-	-0.88	mA		
	KRA308			-	-	-0.36			
	KRA309			-	-	-0.16			
Switching Time	Rise Time	KRA307	t <sub>r</sub>	V <sub>O</sub> =-5V, V <sub>IN</sub> =-5V R <sub>L</sub> =1k Ω	-	0.07	-	μS	
		KRA308			-	0.20	-		
		KRA309			-	0.38	-		
	Storage Time	KRA307			t <sub>stg</sub>	-	1.1		-
		KRA308				-	1.3		-
		KRA309				-	0.7		-
	Fall Time	KRA307			t <sub>f</sub>	-	0.35		-
		KRA308				-	0.4		-
		KRA309				-	0.48		-

Note : \* Characteristic of Transistor Only.

# KRA307~KRA309



# KRA307~KRA309

